







	<h2 style="color: #E67E22;">FQB4N20TM</h2>
 <p>Image may be representation. See specs for product details.</p>	Hersteller-Teilenummer: FQB4N20TM
	Hersteller / Marke: Fairchild/ON Semiconductor
	Teil der Beschreibung: MOSFET N-CH 200V 3.6A D2PAK
	Datenblätter:  FQB4N20TM.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 32363 pcs Stock Available.
	Liefern von: Hong Kong
Versandweg: DHL/Fedex/TNT/UPS/EMS	

Spezifikationen

Teilenummer	FQB4N20TM
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 200V 3.6A D2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	32363 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D ² PAK (TO-263AB)
Verlustleistung (max)	3.13W (Ta), 45W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	200V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	3.6A (Tc)
Rds On (Max) @ Id, Vgs	1.4 Ohm @ 1.8A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	6.5nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	220pF @ 25V
Verpackung	Tape & Reel (TR)















































FQB4N20TM ist neu im Original, Suche FQB4N20TM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB4N20TM Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB4N20TM: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQB4N25TM Fairchild/ON Semiconductor MOSFET N-CH 250V 3.6A D2PAK</p>	 <p>FQB4N20TM AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 3.6A D2PAK</p>	 <p>FQB4N20TM VB FQB4N20TM VB</p>	 <p>FQB4N25TM AMI Semiconductor / ON Semiconductor MOSFET N-CH 250V 3.6A D2PAK</p>
 <p>FQB4N20LTM AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 3.8A D2PAK</p>	 <p>FQB4N20LTM Fairchild/ON Semiconductor MOSFET N-CH 200V 3.8A D2PAK</p>	 <p>FQB4N20 VB FQB4N20 VB</p>	 <p>FQB47P06TM_AM002 Fairchild/ON Semiconductor MOSFET P-CH 60V 47A D2PAK</p>

heiße Teile

Mehr

 FQB3N25TM	 FQB3N30TM	 FQB3N30TM	 FQB3N40TM	 FQB3N40TM
 FQB3N60C	 FQB3N80TM	 FQB3N80TM	 FQB3N90TM	 FQB3N90TM
 FQB3P20TM	 FQB3P20TM	 FQB3P50TM	 FQB3P50TM	 FQB44N10
 FQB44N10TM	 FQB44N10TM	 FQB46N15	 FQB46N15TM	 FQB47P06
 FQB47P06TM	 FQB4N20L	 FQB4N20LTM	 FQB4N20LTM	 FQB4N20TM
 FQB4N25TM	 FQB4N25TM	 FQB4N20TM	 FQB4N50TM	 FQB4N50TM
 FQB4N60C	 FQB4N80TM	 FQB4N80TM	 FQB4N90TM	 FQB4N90TM
 FQB4P25TM	 FQB4P25TM	 FQB50N03	 FQB50N06	 FQB50N06C
 FQB50N06L	 FQB50N06LTM	 FQB50N06LTM	 FQB50N06M	 FQB50N06TM
 FQB50N06TM	 FQB50N06TM-NL	 FQB55N06TM	 FQB55N06TM	 FQB55N10

Contact us: Info@Y-IC.com

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